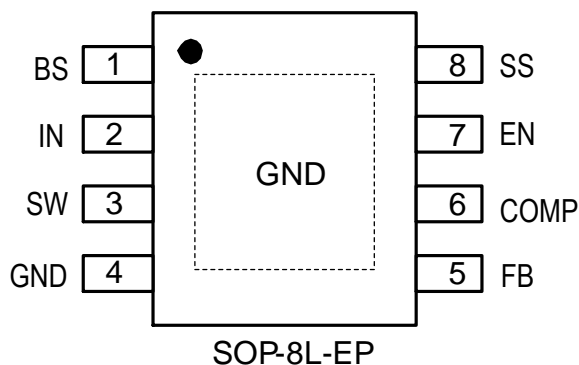


❖ PIN ASSIGNMENT

The package of AX3484 is SOP-8L-EP; the pin assignment is given by:
(Top View)



Name	Description
BS	High-Side Gate Drive Boost Input. BS supplies the drive for the high-side N-Channel MOSFET switch. Connect a 0.01 μ F or greater capacitor from SW to BS to power the high side switch.
IN	Power Input. IN supplies the power to the IC, as well as the step-down converter switches. Drive IN with a 4.75V to 23V power source. Bypass IN to GND with a suitably large capacitor to eliminate noise on the input to the IC. See Input Capacitor.
SW	Power Switching Output. SW is the switching node that supplies power to the output. Connect the output LC filter from SW to the output load. Note that a capacitor is required from SW to BS to power the high-side switch.
GND	Ground.
FB	Feedback Input. FB senses the output voltage to regulate that voltage. Drive FB with a resistive voltage divider from the output voltage. The feedback threshold is 0.925V. See Setting the Output Voltage.
COMP	Compensation Node. COMP is used to compensate the regulation control loop. Connect a series RC network from COMP to GND to compensate the regulation control loop. In some cases, an additional capacitor from COMP to GND is required. See Compensation Components.
EN	Enable Input. EN is a digital input that turns the regulator on or off. Drive EN high to turn on the regulator, drive it low to turn it off. Pull up with 100k Ω resistor for automatic startup.
SS	Soft-Start Control Input. SS controls the soft start period. Connect a capacitor from SS to GND to set the soft-start period. A 0.1 μ F capacitor sets the soft-start period to 15ms. To disable the soft-start feature, leave SS unconnected.

❖ ORDER/MARKING INFORMATION

Order Information	Top Marking
<p>AX3484 XX X</p> <p>Package Type ES: SOP-8L-EP</p> <p>Packing Blank: Tube A : Taping</p>	<p>Logo ← AX 3 4 8 4 → Part number</p> <p>YYWWX → ID code:internal</p> <p>WW: 01~52</p> <p>Year: 18=2018 19=2019 20=2020 21=2021 22=2022 ⋮ 45=2045</p>

❖ ABSOLUTE MAXIMUM RATINGS (at T_A=25°C)

Characteristics	Symbol	Rating	Unit
Input Voltage	V _{IN}	-0.3 to +24	V
Switch Node Voltage	V _{SW}	-1V to V _{IN} +0.3V	V
Boost Voltage	V _{BS}	V _{SW} - 0.3 to V _{SW} + 6	V
All Other Pins		-0.3 to +6	V
Lead Temperature		260	°C
Storage Temperature		-65 to +150	°C
Junction Temperature	T _J	150	°C
Output Voltage	V _{OUT}	0.925 to 20	V
Ambient Operating Temperature		-40 to +85	°C
Thermal Resistance from Junction to case	θ _{JC}	15	°C/W
Thermal Resistance from Junction to ambient	θ _{JA}	40	°C/W

Note: θ_{JA} is measured with the PCB copper area of approximately 1 in²(Multi-layer).

❖ ELECTRICAL CHARACTERISTICS

 ($V_{IN} = 12V$, $T_A = +25^{\circ}C$, unless otherwise noted.)

Characteristics	Symbol	Conditions	Min	Typ	Max	Units
Operating Voltage	V_{IN}		4.75	-	23	V
Shutdown Supply Current	I_{SD}	$V_{EN} = 0V$	-	1	3.0	μA
Feedback Voltage	V_{FB}	$4.75V \leq V_{IN} \leq 23V$	0.900	0.925	0.950	V
High-Side Switch On Resistance (Note)	$R_{DS(ON)1}$		-	100	-	m Ω
Low-Side Switch On Resistance (Note)	$R_{DS(ON)2}$		-	100	-	m Ω
High-Side Switch Leakage Current		$V_{EN} = 0V, V_{SW} = 0V$	-	-	10	μA
Switch Current Limit			3.8	-	-	A
Oscillation Frequency	F_{OSC1}		280	350	430	KHz
Short Circuit Oscillation Frequency	F_{OSC2}	$V_{FB} = 0V$	-	90	-	KHz
Maximum Duty Cycle	D_{MAX}	$V_{FB} = 0.8V$	-	90	-	%
EN Shutdown Threshold Voltage	ENH	V_{EN} Rising	1.1	1.5	2.0	V
EN Shutdown Threshold Voltage Hysteresis			-	210	-	mV
EN Lookout Threshold Voltage			2.4	2.7	3.0	V
EN Lookout Hysteresis			-	210	-	mV
Soft-Start Current	I_{SS}	$V_{SS} = 0V$	-	6	-	μA
Soft-Start Period		$C_{SS} = 0.1\mu F$	-	15	-	ms
Thermal Shutdown	T_{SD}		-	160	-	$^{\circ}C$
Thermal Shutdown Hysteresis	T_{SH}		-	35	-	$^{\circ}C$

Note: Guaranteed by design.

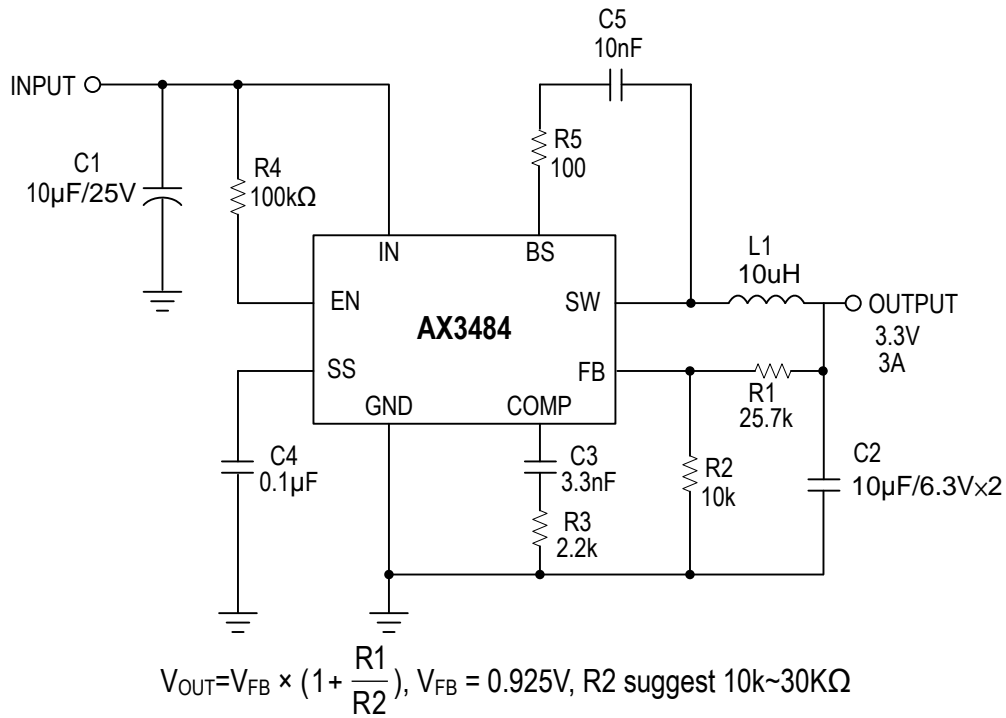
❖ APPLICATION CIRCUIT


Table Recommended Component Selection

V _{IN} (V)	V _{OUT} (V)	R1 (KΩ)	R2 (KΩ)	R3 (KΩ)	C3 (nF)	L1 (μH)	C _{OUT} (μF)
12	5	44.1	10	2.2	3.3	15	10 X 2
5 or 12	3.3	25.7	10	2.2	3.3	10	10 X 2
5 or 12	1.8	9.5	10	2.2	3.3	4.7	10 X 2
5 or 12	1.2	3	10	2.2	3.3	3.3	10 X 2
5 or 12	1	0.81	10	2.2	3.3	2.2	10 X 2

❖ FUNCTION DESCRIPTIONS

The AX3484 is a synchronous rectified, current-mode, step-down regulator. It regulates input voltages from 4.75V to 23V down to an output voltage as low as 0.925V, and supplies up to 3A of load current.

The AX3484 uses current-mode control to regulate the output voltage. The output voltage is measured at FB through a resistive voltage divider and amplified through the internal Transconductance error amplifier. The voltage at the COMP pin is compared to the switch current measured internally to control the output voltage.

The converter uses internal N-Channel MOSFET switches to step-down the input voltage to the regulated output voltage. Since the high side MOSFET requires a gate voltage greater than the input voltage, a boost capacitor connected between SW and BS is needed to drive the high side gate. The boost capacitor is charged from the internal 5V rail when SW is low.

❖ APPLICATION INFORMATION

COMPONENT SELECTION

Setting the Output Voltage

The output voltage is set using a resistive voltage divider from the output voltage to FB pin. The voltage divider divides the output voltage down to the feedback voltage by the ratio:

$$V_{FB} = V_{OUT} \times \frac{R2}{R1 + R2}$$

Where V_{FB} is the feedback voltage and V_{OUT} is the output voltage.
Thus the output voltage is:

$$V_{OUT} = 0.925 \times \frac{R1 + R2}{R2}$$

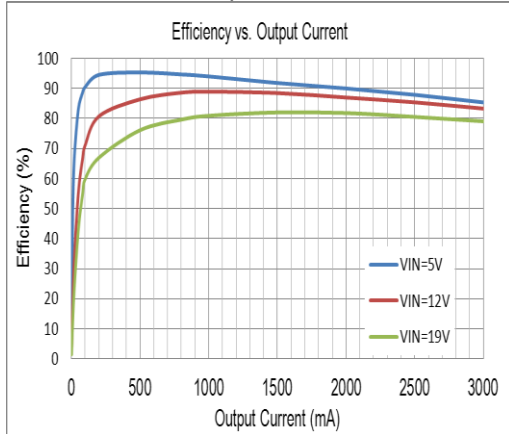
$R2$ can be as high as 100k Ω , but a typical value is 10k Ω . Using the typical value for $R2$, $R1$ is determined by:

$$R1 = 10.811 \times (V_{OUT} - 0.925) \text{ (k}\Omega\text{)}$$

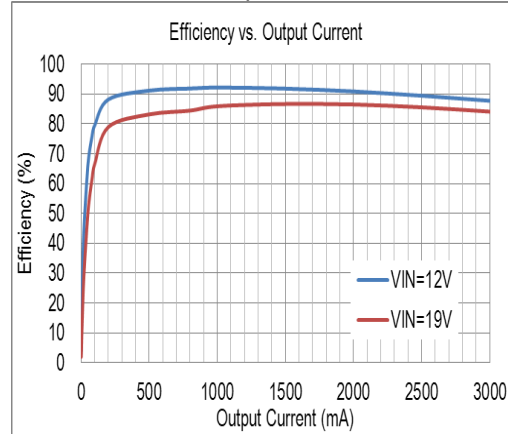
For example, for a 3.3V output voltage, $R2$ is 10k Ω , and $R1$ is 25.7k Ω .

❖ TYPICAL CHARACTERISTICS

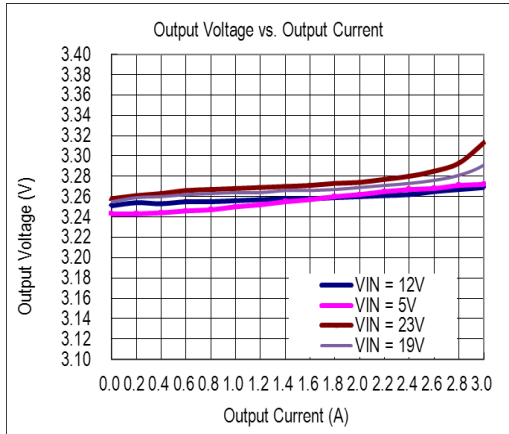
Output=3.3V



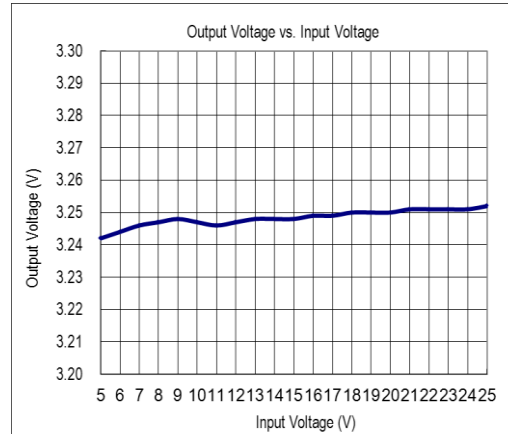
Output=5V



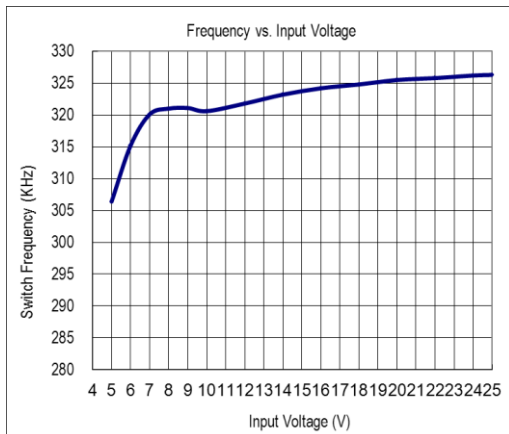
Output Voltage vs. Output Current



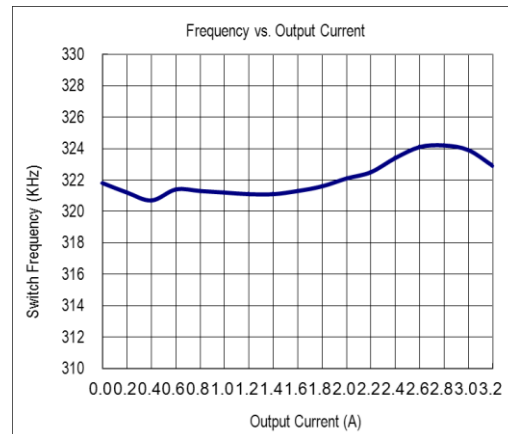
Output Voltage vs. Input Voltage

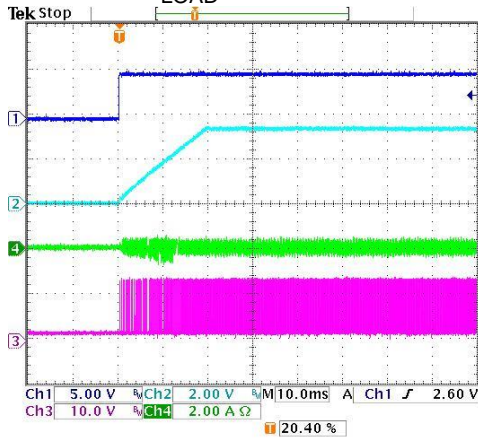
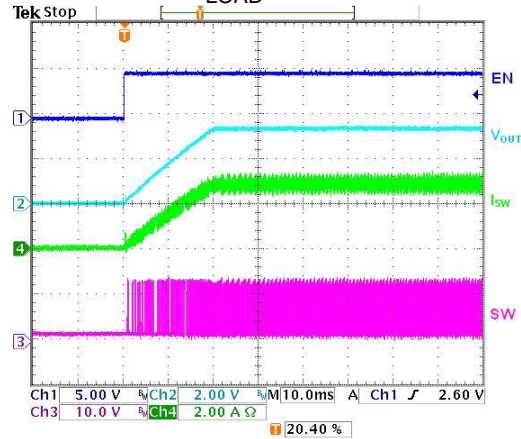
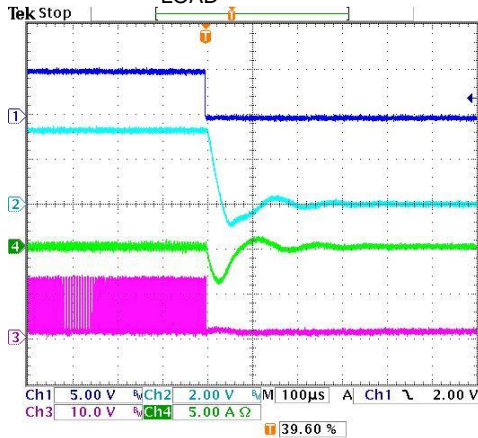
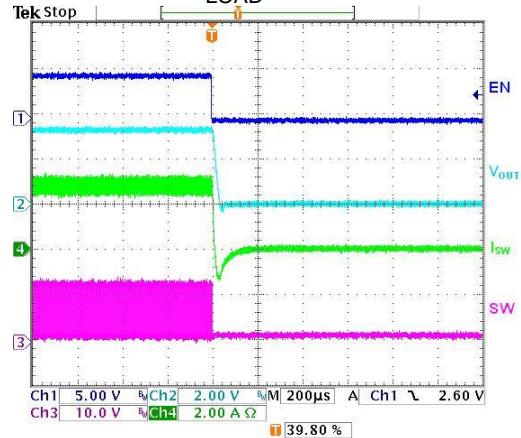
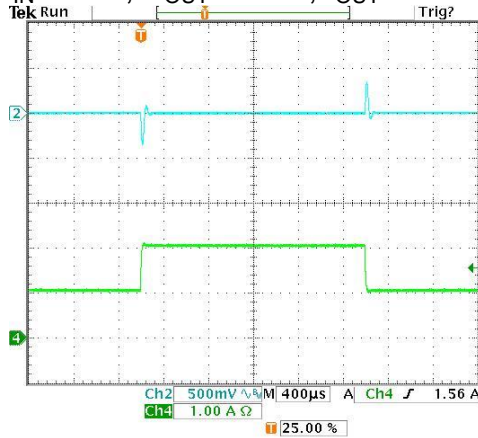
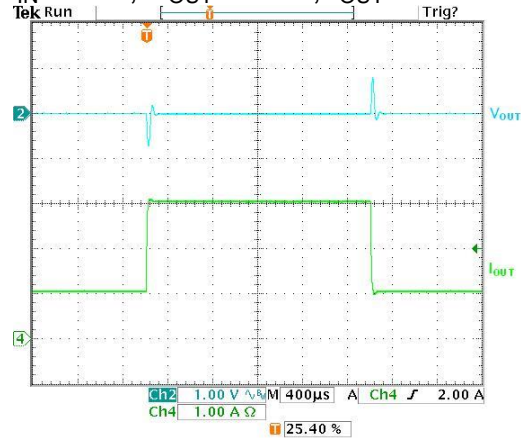


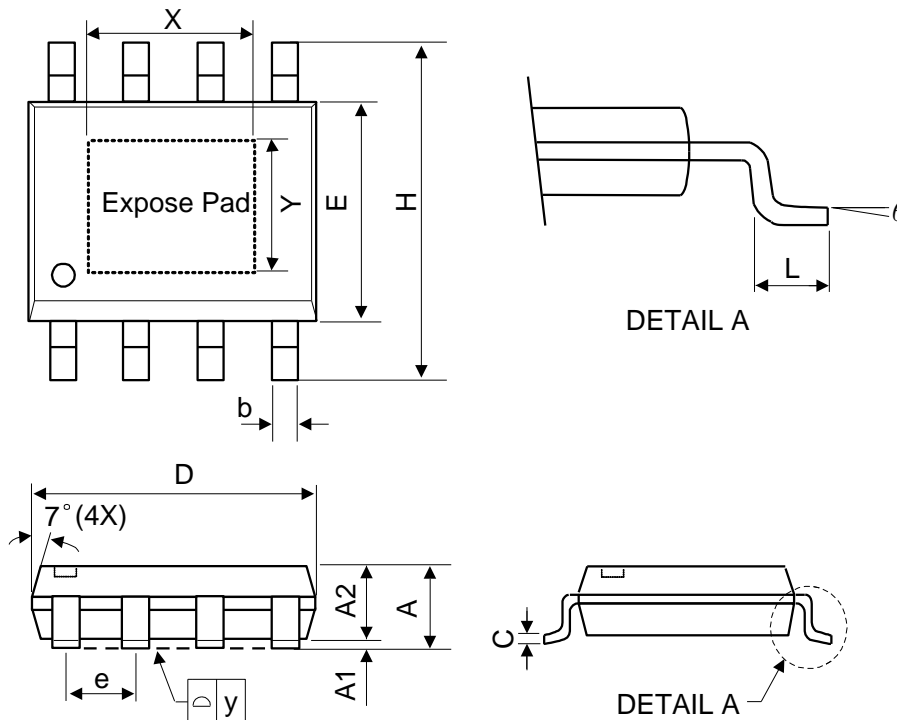
Frequency vs. Input Voltage



Frequency vs. Output Current



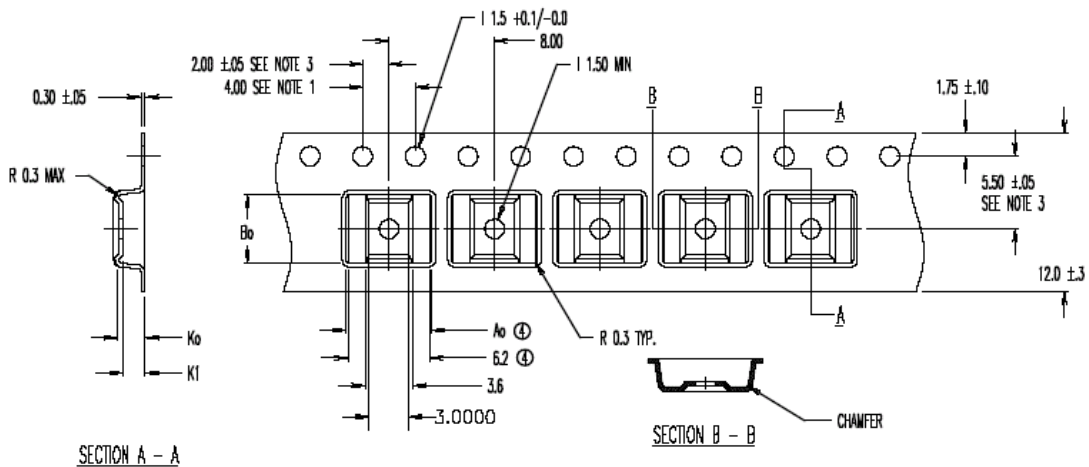
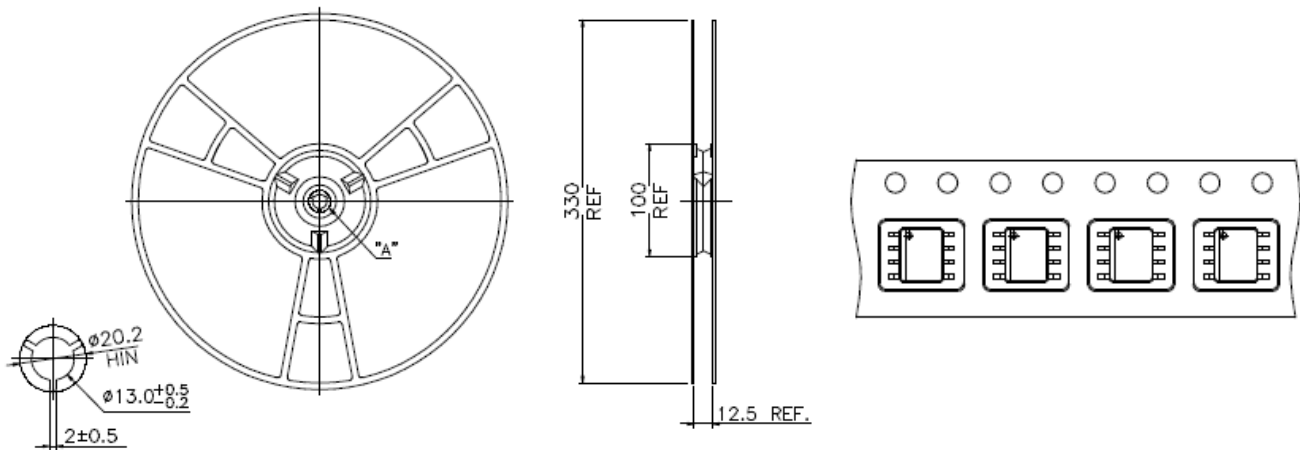
❖ TYPICAL CHARACTERISTICS (COUNTINOUS)
 $V_{IN} = 12V, V_{OUT} = 3.3V,$
 $I_{LOAD} = \text{No Load}$

 $V_{IN} = 12V, V_{OUT} = 3.3V,$
 $I_{LOAD} = 3A$

 $V_{IN} = 12V, V_{OUT} = 3.3V,$
 $I_{LOAD} = \text{No Load}$

 $V_{IN} = 12V, V_{OUT} = 3.3V,$
 $I_{LOAD} = 3A$

 $V_{IN} = 12V, V_{OUT} = 3.3V, I_{OUT} = 1A \leftrightarrow 2A$

 $V_{IN} = 12V, V_{OUT} = 3.3V, I_{OUT} = 1A \leftrightarrow 3A$


❖ PACKAGE OUTLINES


Symbol	Dimensions in Millimeters			Dimensions in Inches		
	Min.	Nom.	Max.	Min.	Nom.	Max.
A	-	-	1.75	-	-	0.069
A1	0	-	0.15	0	-	0.06
A2	1.25	-	-	0.049	-	-
C	0.1	0.2	0.25	0.0075	0.008	0.01
D	4.7	4.9	5.1	0.185	0.193	0.2
E	3.7	3.9	4.1	0.146	0.154	0.161
H	5.8	6	6.2	0.228	0.236	0.244
L	0.4	-	1.27	0.015	-	0.05
b	0.31	0.41	0.51	0.012	0.016	0.02
e	1.27 BSC			0.050 BSC		
y	-	-	0.1	-	-	0.004
X	-	2.34	-	-	0.092	-
Y	-	2.34	-	-	0.092	-
θ	0°	-	8°	0°	-	8°

Mold flash shall not exceed 0.25mm per side

JEDEC outline: MS-012 BA

❖ Carrier tape dimension
ESOP8L


⊕ \ominus $A_0 = 6.50$
 $B_0 = 5.20$
 $K_0 = 2.10$
 $K_1 = 1.70$

Notes:

1. 10 sprocket hole pitch cumulative tolerance ± 0.2 mm
2. Camber not to exceed 1mm in 100mm.
3. Material: Anti-Static Black Advantek Polystyrene.
4. A_0 and B_0 measured on a plane 0.3mm above the bottom of the pocket.
5. K_0 measured from a plane on the inside bottom of the pocket to the top surface of the carrier.
6. Pocket position relative to sprocket hole measured as true position of pocket, not pocket hole.